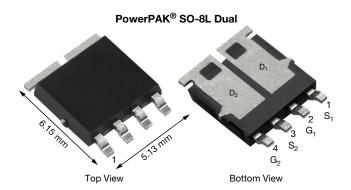


Vishay Siliconix

Automotive Dual N-Channel 30 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY				
V _{DS} (V)	30			
$R_{DS(on)}$ (Ω) at $V_{GS} = 10 \text{ V}$	0.0120			
$R_{DS(on)}$ (Ω) at $V_{GS} = 4.5 \text{ V}$	0.0170			
I _D (A)	30			
Configuration	Dual			

FEATURES

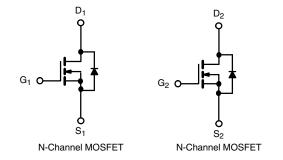
- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





HALOGEN

FREE



ORDERING INFORMATION	
Package	PowerPAK SO-8L
Lead (Pb)-free and halogen-free	SQJ914EP-T1 (for detailed order number please see www.vishay.com/doc?79771)

ABSOLUTE MAXIMUM RATINGS	(T _C = 25 °C, unles	s otherwise noted	i)	
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V _{DS}	30	V
Gate-source voltage		V_{GS}	± 20	V
Continuous drain current	T _C = 25 °C ^a	1	30	
Continuous drain current	T _C = 125 °C	I _D	19	
Continuous source current (diode conduction))	I _S	25	Α
Pulsed drain current ^b		I _{DM}	90	
Single pulse avalanche current	L = 0.1 mH	I _{AS}	22	
Single pulse avalanche energy	L = 0.1 mm	E _{AS}	24.2	mJ
Maximum power dissipation ^b	T _C = 25 °C	В	27	W
viaximum power dissipation ~	T _C = 125 °C	P_{D}	9	VV
$I_{C} = 125 ^{\circ}C$ Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C
Soldering recommendations (peak temperatur	re) ^{d, e}	-	260	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount c	R _{thJA}	85	°C/W
Junction-to-case (drain)		R_{thJC}	5.5	C/VV

Notes

- a. Package limited
- b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %
- c. When mounted on 1" square PCB (FR4 material)
- d. See solder profile (www.vishay.com/doc?73257). The PowerPAK SO-8L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components



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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static					•		
Drain-source breakdown voltage	V_{DS}	$V_{GS} = 0$, $I_D = 250 \mu A$		30	-	-	V
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μA	1.5	2.0	2.5	V
Gate-source leakage	I _{GSS}	V _{DS} =	$= 0 \text{ V}, \text{ V}_{GS} = \pm 20 \text{ V}$	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = 30 V	-	-	1	
Zero gate voltage drain current	I_{DSS}	$V_{GS} = 0 V$	V _{DS} = 30 V, T _J = 125 °C	-	-	50	μΑ
		$V_{GS} = 0 V$	V _{DS} = 30 V, T _J = 175 °C	-	-	250	
On-state drain current ^a	$I_{D(on)}$	V _{GS} = 10 V	$V_{DS} \ge 5 \text{ V}$	15	-	-	Α
		V _{GS} = 10 V	$I_D = 4.5 A$	-	0.0098	0.0120	
Drain-source on-state resistance ^a	R-ac	$V_{GS} = 4.5 \text{ V}$	$I_D = 3 A$	-	0.0139	0.0170	Ω
Diditi-Source off-State resistance	R _{DS(on)}	V _{GS} = 10 V	I _D = 4.5 A, T _J = 125 °C	-	-	0.0188	1 12
		V _{GS} = 10 V	I _D = 4.5 A, T _J = 175 °C	-	-	0.0227	
Forward transconductance b	9 _{fs}	V _{DS}	$I_{D} = 15 \text{ V}, I_{D} = 4 \text{ A}$	-	25	-	S
Dynamic ^b							
Input capacitance	C_{iss}			-	850	1110	
Output capacitance	C_{oss}	$V_{GS} = 0 V$	V _{DS} = 15 V, f = 1 MHz	-	167	220	рF
Reverse transfer capacitance	C_{rss}			-	60	80	
Total gate charge ^c	Qg			-	15	25	
Gate-source charge ^c	Q _{gs}	$V_{GS} = 10 \text{ V}$	$V_{DS} = 15 \text{ V}, I_D = 5 \text{ A}$	-	3	-	nC
Gate-drain charge ^c	Q_{gd}			-	3	-	
Gate resistance	Rg		f = 1 MHz	0.7	1.6	2.5	Ω
Turn-on delay time ^c	t _{d(on)}			-	11	20	
Rise time ^c	t _r		$V_{DD} = 15 \text{ V}, \text{ R}_{L} = 3.8 \Omega$ $I_{D} \cong 4 \text{ A}, \text{ V}_{GEN} = 10 \text{ V}, \text{ R}_{g} = 1 \Omega$		5	10	ns ns
Turn-off delay time ^c	t _{d(off)}	$I_D \cong 4 A$,			21	40	
Fall time ^c	t _f			-	5	10	
Source-Drain Diode Ratings and Charac	teristics ^b						
Pulsed current ^a	I _{SM}			-	-	90	Α
Forward voltage	V_{SD}	l _F =	I _F = 4 A, V _{GS} = 0 V		0.79	1.2	V
Body diode reverse recovery time	t _{rr}			-	22	50	ns
Body diode reverse recovery charge	Q _{rr}] , ,	A di/dt = 100 A/up	-	18	40	nC
Reverse recovery fall time	ta	IF = 3 /	A, di/dt = 100 A/μs	-	14		
Reverse recovery rise time	t _b]		-	8	-	ns
Body diode peak reverse recovery current	I _{RM(REC)}			-	-1.4	-	Α

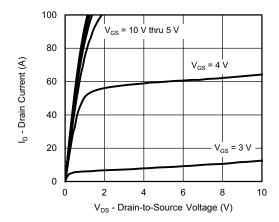
Notes

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

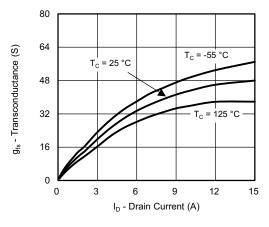
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



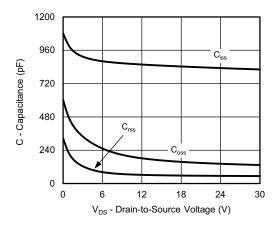
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



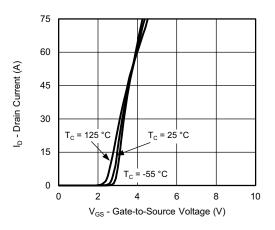
Output Characteristics



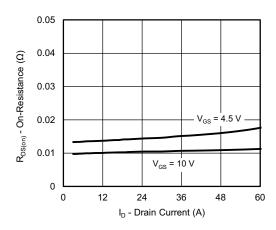
Transconductance



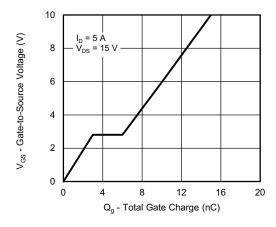
Capacitance



Transfer Characteristics



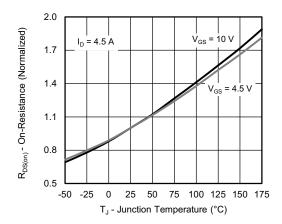
On-Resistance vs. Drain Current



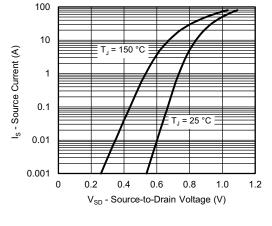
Gate Charge



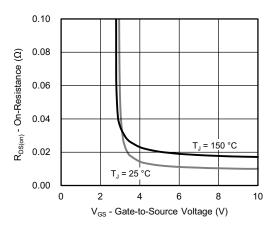
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



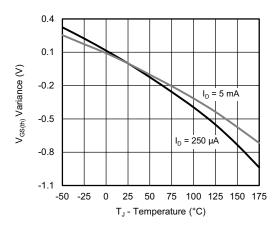
On-Resistance vs. Junction Temperature



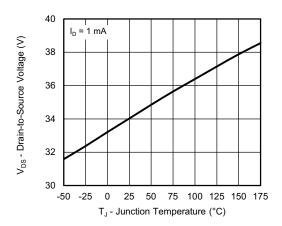
Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



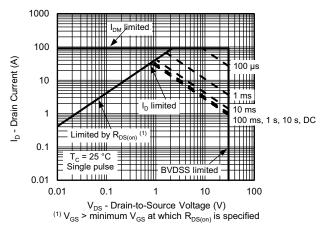
Threshold Voltage



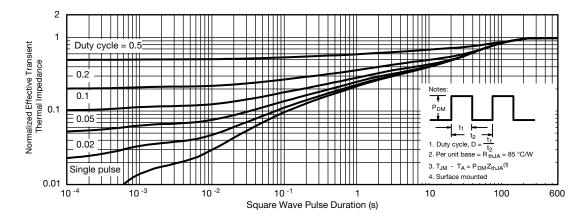
Drain Source Breakdown vs. Junction Temperature



THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)



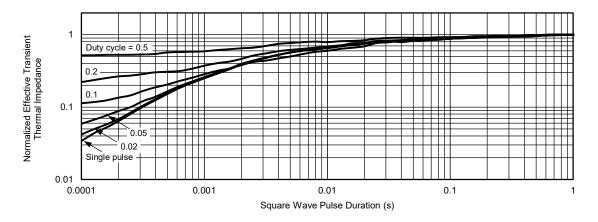
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

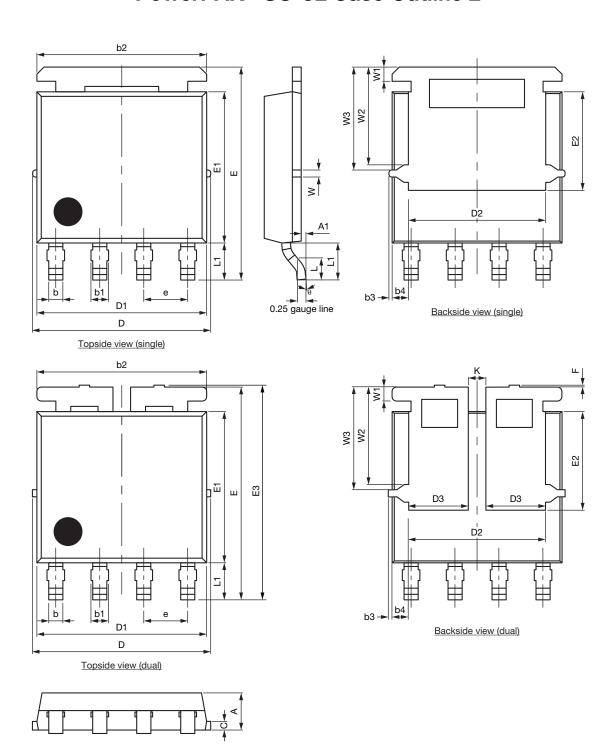
Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg277311.



PowerPAK® SO-8L Case Outline 2





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DIM	MILLIMETERS			INCHES			
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX	
Α	1.00	1.07	1.14	0.039	0.042	0.045	
A1	0.00	-	0.127	0.00	-	0.005	
b	0.33	0.41	0.48	0.013	0.016	0.019	
b1	0.44	0.51	0.58	0.017	0.020	0.023	
b2	4.80	4.90	5.00	0.189	0.193	0.197	
b3		0.094		0.004			
b4		0.47			0.019		
С	0.20	0.25	0.30	0.008	0.010	0.012	
D	5.00	5.13	5.25	0.197	0.202	0.207	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.86	3.96	4.06	0.152	0.156	0.160	
D3	1.63	1.73	1.83	0.064	0.068	0.072	
е		1.27 BSC		0.050 BSC			
Е	6.05	6.15	6.25	0.238	0.242	0.246	
E1	4.27	4.37	4.47	0.168	0.172	0.176	
E2	2.75	2.85	2.95	0.108	0.112	0.116	
E3	6.05	6.22	6.40	0.238	0.245	0.252	
F	-	-	0.15	-	-	0.006	
L	0.62	0.72	0.82	0.024	0.028	0.032	
L1	0.92	1.07	1.22	0.036	0.042	0.048	
K		0.51			0.020		
W	0.23			0.009			
W1		0.41			0.016		
W2		2.82		0.111			
W3		2.96			0.117		
θ	0°	-	10°	0°	-	10°	

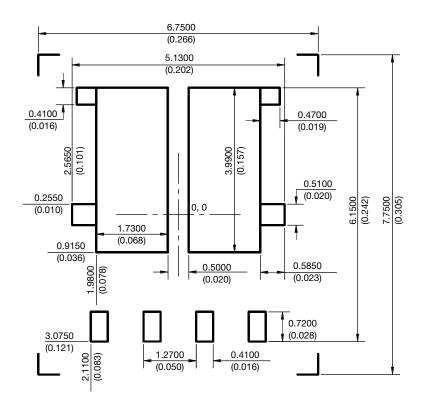
DWG: 6044

Note

• Millimeters will govern



RECOMMENDED MINIMUM PAD FOR PowerPAK® SO-8L DUAL



Recommended Minimum Pads Dimensions in mm (inches) Keep-out 6.75 (0.266) x 7.75 (0.305)



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Vishay

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